ememory

A Leading Logic NVM Company

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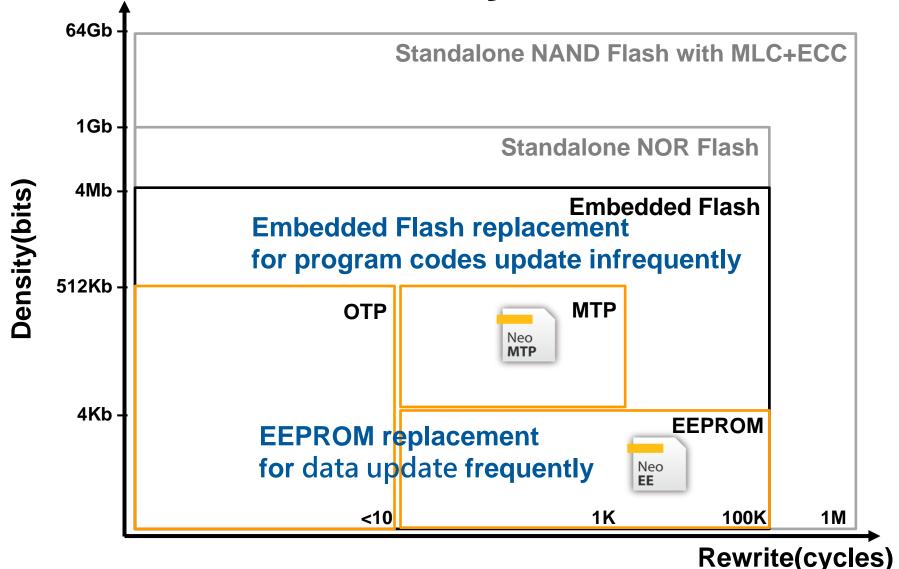
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Outline

- Business Model
- Review of Operations
- Growth Opportunity and Future Outlook
- Q & A

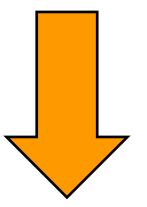


Nonvolatile Memory Classifications



What's Logic Non-Volatile Memory (NVM)

Embedded NVM = LOGIC + 10 Masks



30% more cost reduction

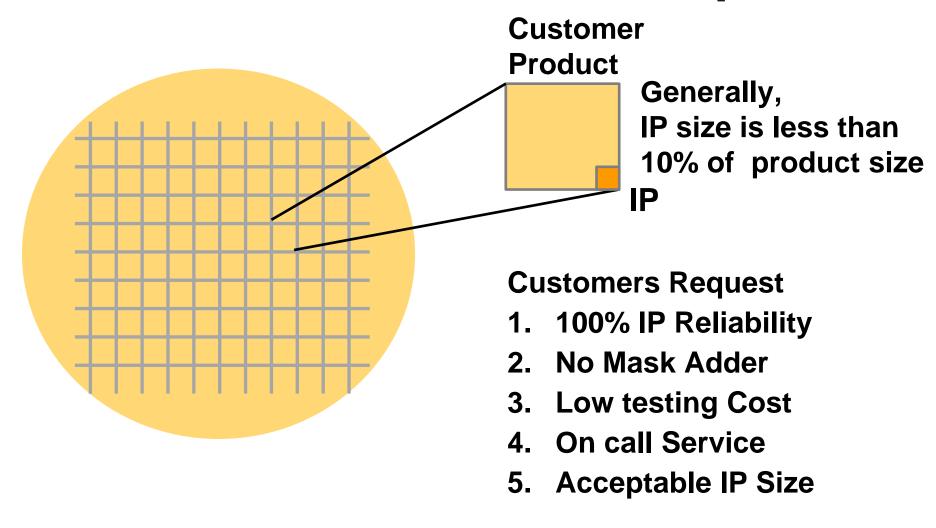
Embedded LOGIC NVM = LOGIC



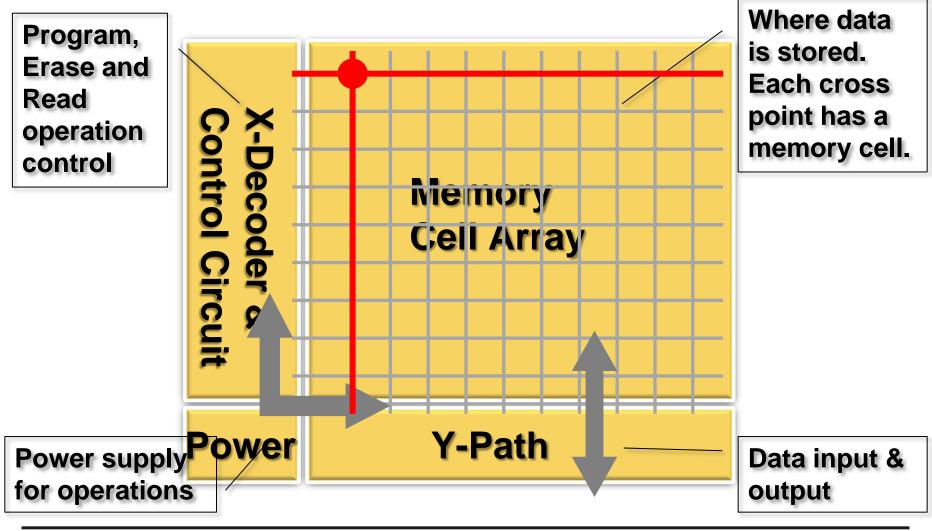
Embedded NVM Technologies

	ROM	eFuse (OTP)	Antifuse (OTP)	CMOS Floating Gate (OTP)	CMOS Floating Gate (MTP)	Embedded Flash
Cell Structure	Transistor	Poly Fuse	Antifuse	Floating Gate	Floating Gate	Floating Gate
Standard CMOS Compatible	Yes	Yes	Yes	Yes	Yes	No
Bitcell Area	<1	50	1	2	4	1
Endurance	No	No	< 10	< 10	10K-100K	100-1000K
Density	4Kb-1Mb	256bit-4Kb	16bit-1Mb	16Kb-1Mb	1Kb-2M	64Kb-4Mb
Security	Low	Low	High	High	High	High
Additional Steps	None	None	None	None	None	+10 Mask

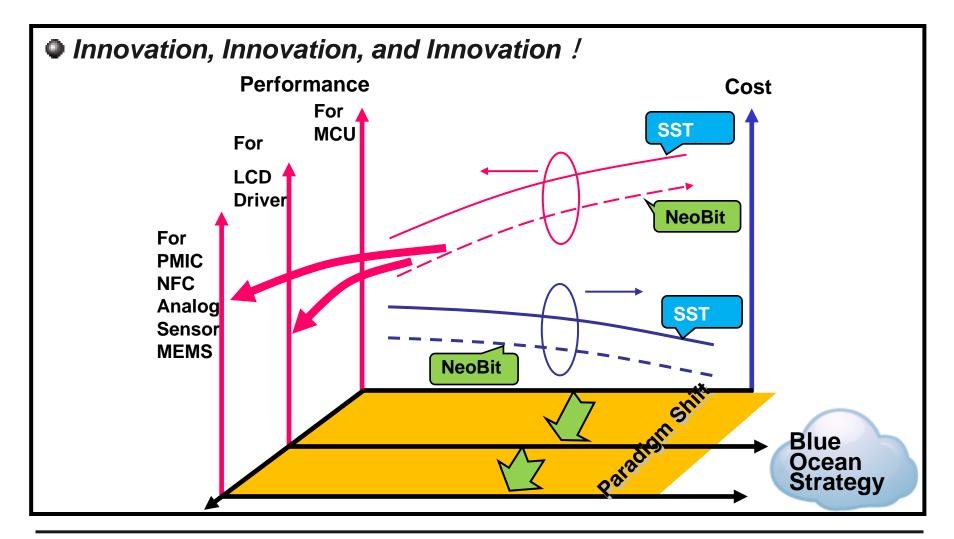
Considerations for IP Adoption



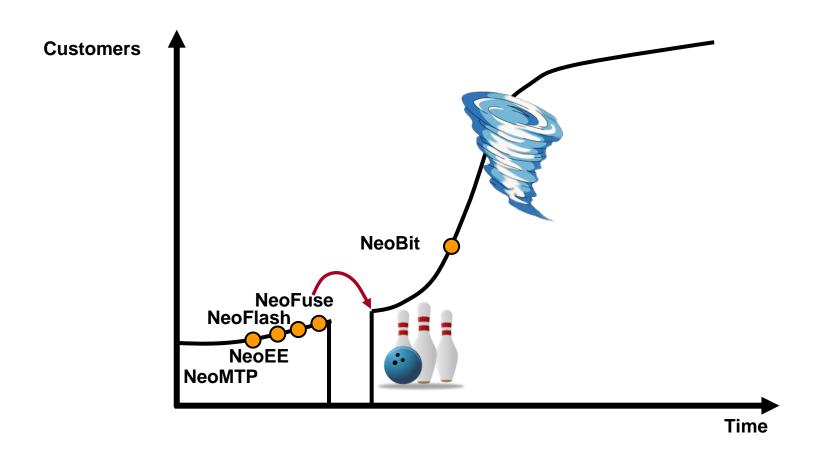
Inside Nonvolatile Memory IP



What We Have Done



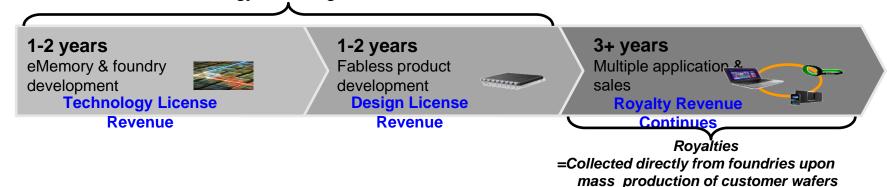
Crossing the Chasm



Business Model

- Founded in 2000. First customer engaged in 2002. Achieved profitability in 2005 and IPO in 2011. The largest logic non-volatile memory IP company, 220 employees (149 R&D).
- Since its IPO, the company initiated no new fund raising or bank debt, and has distributed in excess of 100% of earnings in cash dividends.
- Growth Indices: 1) No. of on-going technology platforms
 - 2) No. of design licenses
 - 3) Royalty

Upfront Licensing Fee =Technology and Design License



Worldwide Customers



	Taiwan	China	Korea	Japan	North America	Europe	Others
Foundry	5	6	3	2	1	1	1
IDM	0	0	0	8	2	1	0
Fabless	226	331	49	31	168	80	31



























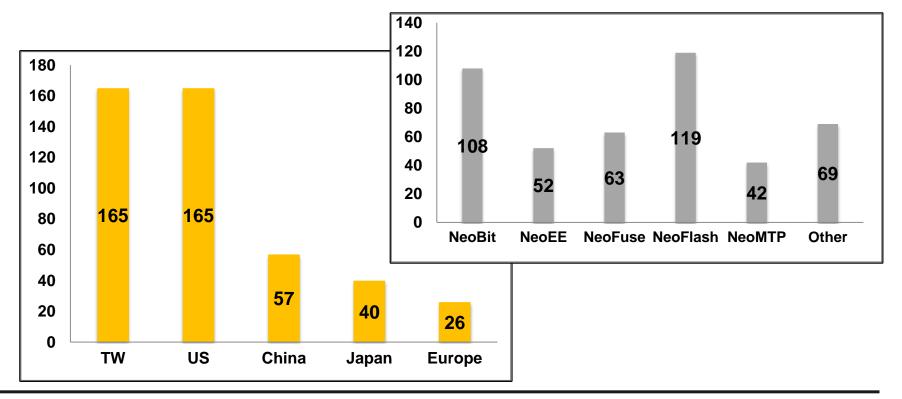






Patent Portfolio

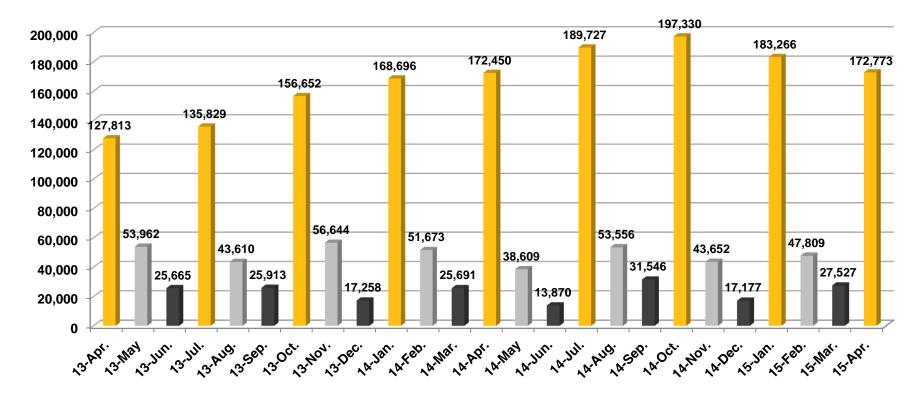
	4Q14	1Q15	Diff.
Pending	166	175	+9
Issued	269	278	+9
Total	435	453	+18



Quarterly Revenue Pattern

• The quarterly royalty from most of foundries are collected at first month of each quarter and from some other foundries are collected at second month, and none at third month.

Unit: NTD Thousands



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1Q Revenue Breakdown

Unit: NTD thousands

	1Q15	4Q14	% change	1Q14	% change	2014	2013	% change
Licensing	64,056	51,849	23.54%	75,045	-14.64%	246,073	245,688	0.16%
Royalty	194,546	206,310	-5.70%	171,015	13.76%	757,904	562,570	34.72%
Total	258,602	258,159	0.17%	246,060	5.10%	1,003,977	808,258	24.21%

Unit: Number of contracts

		1Q15	4Q14	2014	2013
Technology Licenses		5	3	21	19
Design	NRE	21	15	82	51
Licenses	Usage	82	99	363	342

Financial Income Statement

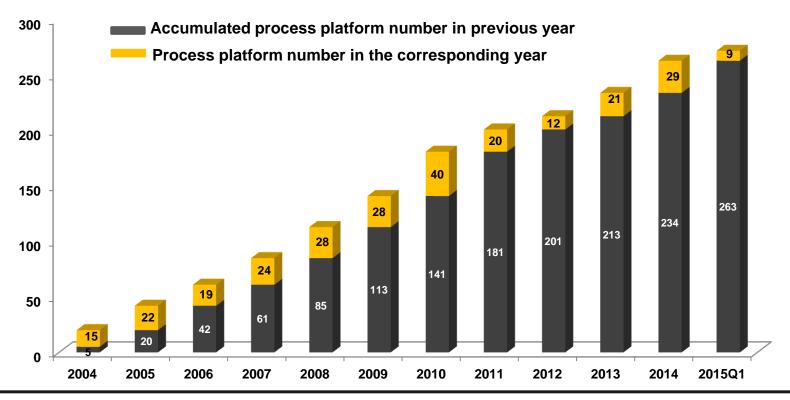
(Unit: NTD thousands)	1Q15	4Q14	% change	1Q14	% change
Revenue	258,602	258,159	0.2%	246,060	5.1%
Gross Margin	100%	100%	-	100%	-
Operating Expenses	128,976	148,501	-13.1%	126,719	1.8%
Operating Margin	50.1%	42.5%	+7.6ppts	48.5%	+1.6ppts
Net Income	114,423	100,896	13.4%	110,936	3.1%
Net Margin	44.2%	39.1%	+5.1ppts	45.1%	-0.9ppts
EPS (Unit: NTD)	1.51	1.33	13.5%	1.46	3.4%
ROE	24.8%	23.4%	+1.4ppts	25.8%	-1.0ppts

Technology License

Unit: Number of contract

Year	2012	2013	2014	20151Q
License number	12	19	21	5

Note: The terms (including number of process platforms and licensing fees) for each technology license are set contractually. Payments are made according to set milestones, and there are no particular seasonal factors involved.



Current Technology Development Platforms

- Total (As of Mar.) : 74*
- 22 for NeoBit, 26 for NeoFuse, 1 for NeoFlash,
 - 17 for NeoEE, and 8 for NeoMTP.

	16nm	28nm	40nm	55/65nm	80/90nm	0.11~ 0.13um	0.15~ 0.18um	>0.25 um	Total
NeoBit	ı	•	-	1	-	8	12	2	22
NeoFuse	1	7	4	8	1	3	2	-	26
NeoFlash	-	-	-	1	-	1	-	-	1
NeoEE	•	-	2	-	1	4	9	1	17
NeoMTP	ı	-	-	1	2	2	3		8

Note*: 9 platforms qualified in 1Q; 5 platforms kicked off in 1Q.

Current Technology Development Platforms

12" Fabs	Production	Development	NVM Type	Process Type
16nm	0	1	OTP	FF+
28nm	2	7	ОТР	LP/HPM, HLP/HPM, LPS
40nm	1	6	OTP, MTP	HV-DDI, LP
55/65nm	9	10	OTP, MTP, Flash	LP, HV-DDI, HV-OLED, DRAM, CIS
80/90nm	5	4	OTP, MTP	HV-DDI, HV-OLED, LP
0.13/0.11um	4	5	OTP, Flash	HV-DDI, BCD, Generic
0.18um	1	0	ОТР	BCD

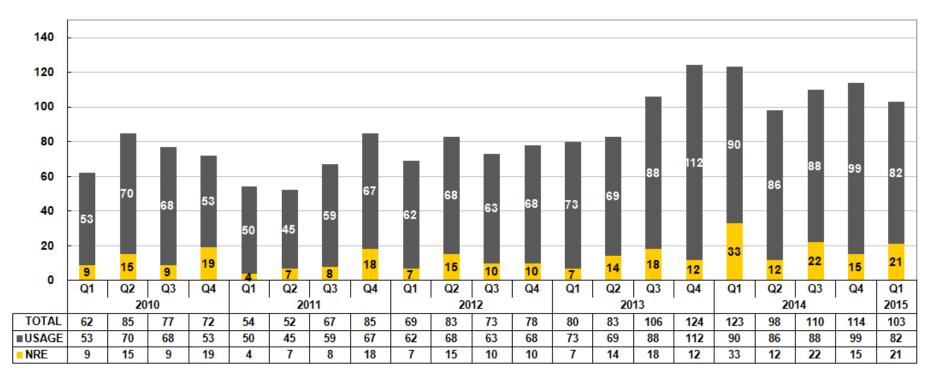
8" Fabs	Development	NVM Type	Process Type
0.13/0.11um	12	OTP, MTP, Flash	HV-DDI, BCD, LP, RF, CIS, LL
0.18/0.16/0.152um	26	OTP, MTP	Generic, LP, LL, MR, HV, Green, BCD
0.25um	2	OTP, MTP	BCD
0.35um	1	ОТР	UHV

*As of Mar. 31, 2015



Quarterly Design Licensing (New Tape Out)

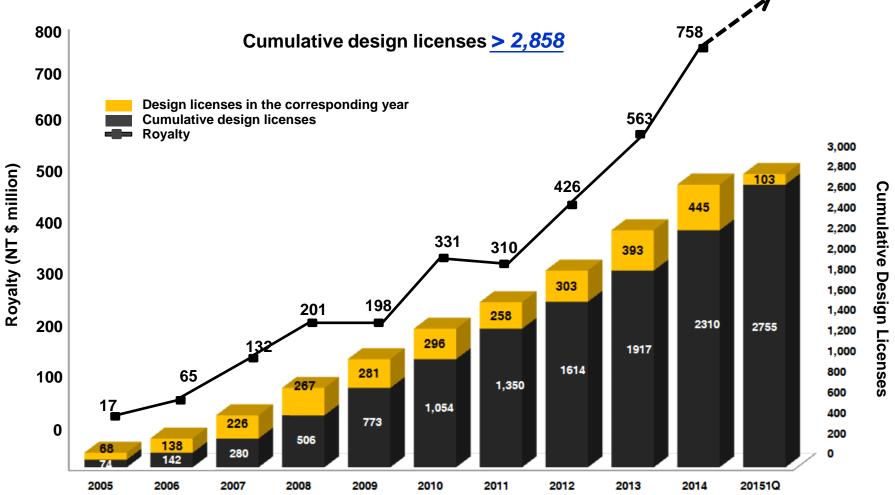
- Total 103 NTO as of 1Q 2015 (445 @2014 393 @2013, 303 @2012, 258 @2011)



Usage: Usage of pre-qualified and verified IP (charged by per product tape out or annual package), the cycle time from design implementation to royalty payments for mass production is faster, typically less than one year.

NRE: NRE covers the customization of IP that must undergo new verification or qualification. It typically requires 1 to 1.5 years before resulting in royalty revenue.

Cumulative Licenses Drive Future Royalties

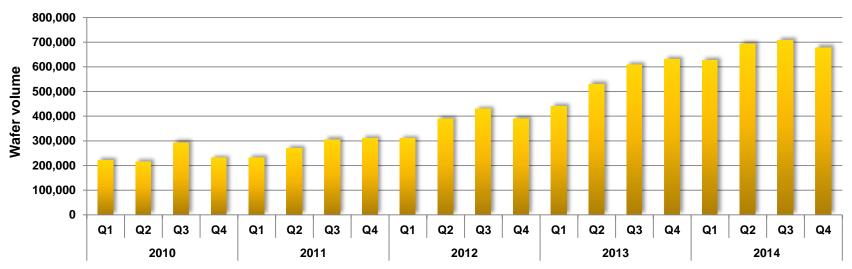


note 1: Due to the 2009 recession, royalty income was down annually 1.5%.

note 2: Pre-payment of royalty fees by a single customer contributed to 2010 annual growth of 67%, causing a drop of 6.3% in the following year, 2011.

note 3: CAGR for 2009-2013 was 30%.

Wafer Production Volume



embedded eMemory IP in T Company (\$revenue); * % of Process node in T company total revenue in 1Q15

	Process node	*% of T	1Q15	4Q14	2014	2013
8"	0.5+	1%	0%	0%	0%	0%
	0.25/0.35	4%	32.1%	30%	30.5%	27.3%
	0.15/0.18	13%	8%	8%	11.9%	10.7%
	0.11/0.13	2%	20.5%	28.9%	20.8%	19.1%
12"	90nm	7%	18.2%	18.2%	16.3%	4.8%
	65nm	12%	0.3%	0.1%	0%	0%
	40/45nm	15%	0%	0%	0%	0%
	28nm	30%	0%	0%	0%	0%
	20nm	16%	0%	0%	0%	0%
8"		20%	14.1%	14.2%	15.6%	14.2%
12"		80%	1.5%	1.4%	1.4%	0.69%
Total		100%	4.1%	4.3%	4.5%	4.1%

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eMemory's NVM Technologies

- Logic NVM portfolio offers one-stop-shop solution.
 - Compatible to any process
- Competitive macro sizes

> Robust structure

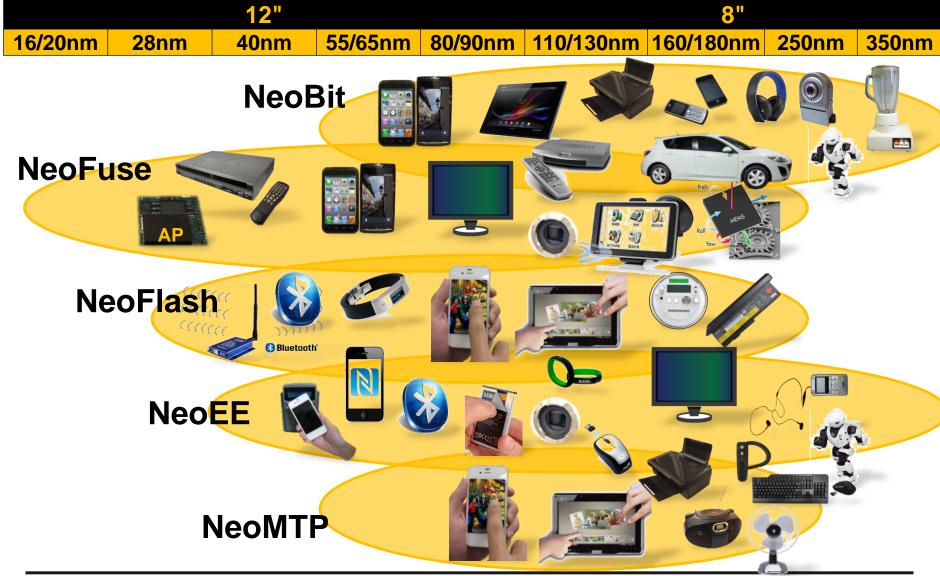
> Easy integration

> Low process cost

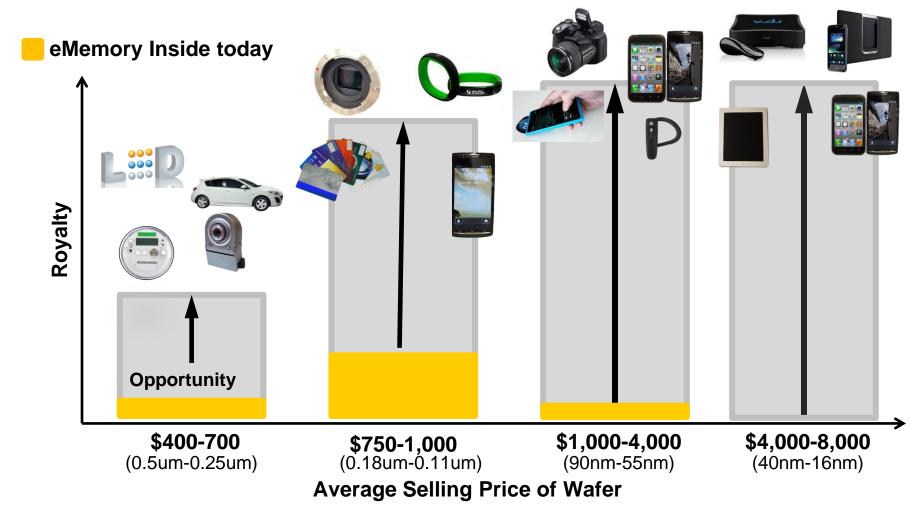
> Easy porting

eMemory's NVM	0	ГР		MTP	
Technology	NeoBit	NeoFuse	NeoFlash	NeoEE	NeoMTP
Product Type	ОТР	ОТР	Flash	EEPROM	MTP
Endurance (Cycles)	10	10	1K~10K	10K~100K	1K~10K
Additional Mask Steps	0	0	2-3	0	0
Technology	Floating gate	Anti-Fuse	SONOS	Floating gate	Floating gate
Scalability	Simple	Simple	Simple	Simple	Simple
Memory Density	HD < 512Kb GHD < 16Mb	< 4Mb	< 2Mb	< 4Kb	< 512Kb

Applications by Technology

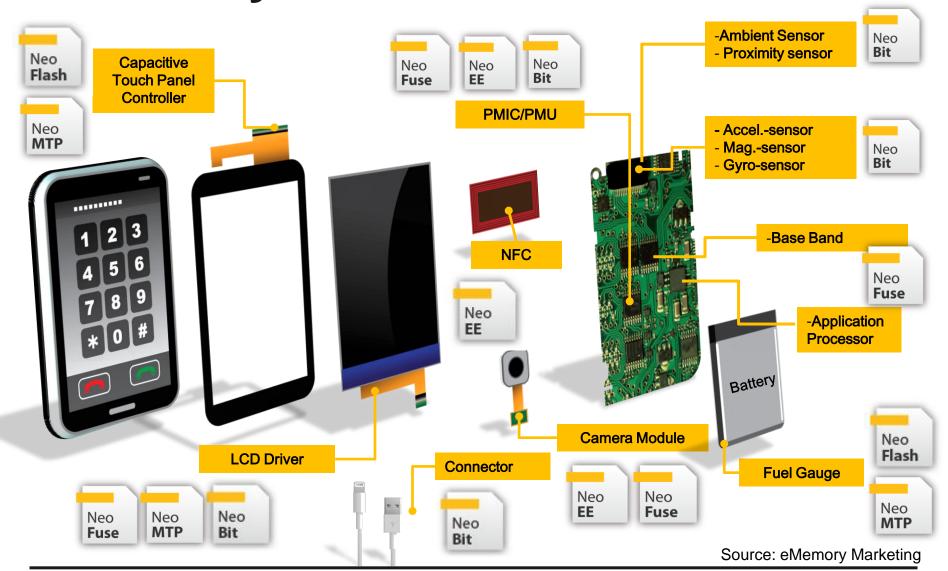


Opportunity at all Price Points



Note: 2.2 million 8" equivalent wafers with eMemory IP were shipped in 2013. (~5% of WW foundry shipment)

eMemory IP in Smart Phone



Benefits from Using eMemory IPs

Design-in for

1. Trimming

NVM IP

- 2. Parameter Setting
- 3. Code Storage
- 4. Identification Setting

Package/FT level

- 1. Trim: SPEC shift
- 2. Parameter Setting: cross chip optimization
- 3. Identification Setting: manufacturer resume
- 4. Function Selection: setting for target market

CP Test Package/FT 5. Encryption **Assembling** 6. Function Selection **IC Design** CP level 1. Trim: output voltage or current 2. Parameter Setting: default value

3. Code Storage: default F/W code

System Assembling

- 1. Parameter Setting: cross chip optimization
- 2. Code Storage: F/W code modification
- 3. Identification Setting: manufacturer resume
- 4. Encryption: Security algorithm or key storage

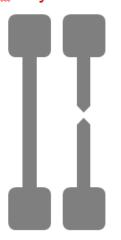
System

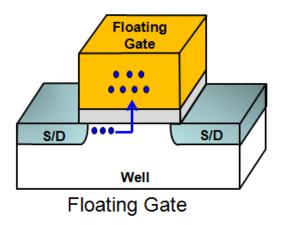
Invisibility for Security

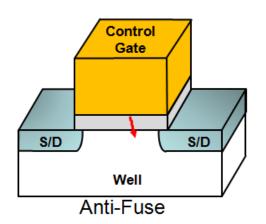
- Provide "Invisible Hardware Key" for invisible storage
- Prevent reverse-engineering to detect content of security key
- Protect firmware and hardware of ICs from pirating
- Extend & protect customer's business

eFuse Key: Data is easily observed

Invisible Hardware Key: Data is hard to be detected



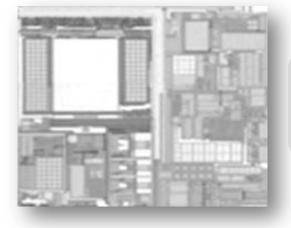






Security & Protection

Authorized Product

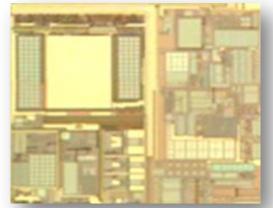


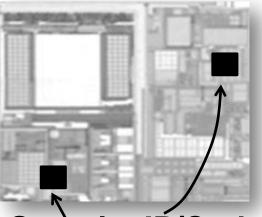
reverse copy

re-produce

without protection







reverse copy

re-produce

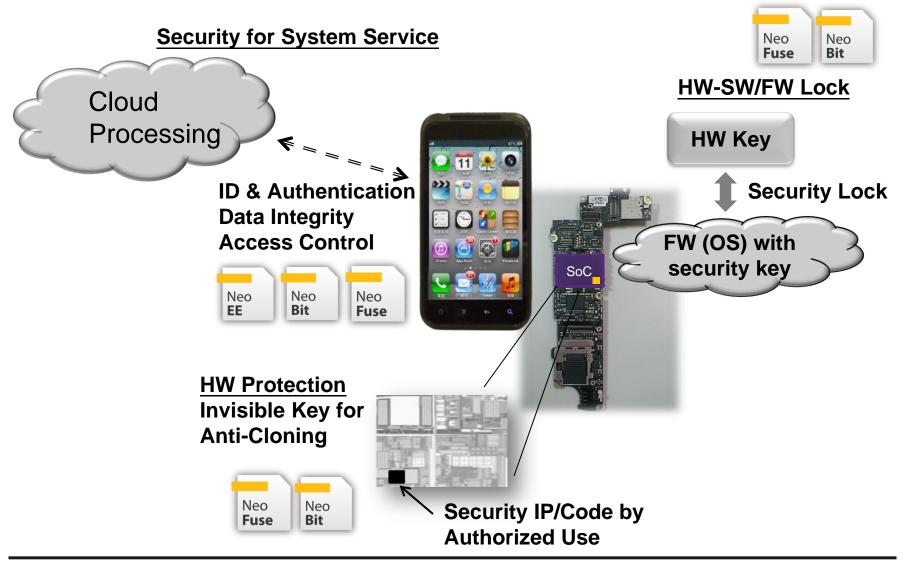
with protection

Security IP/Code by **Authorized Use**

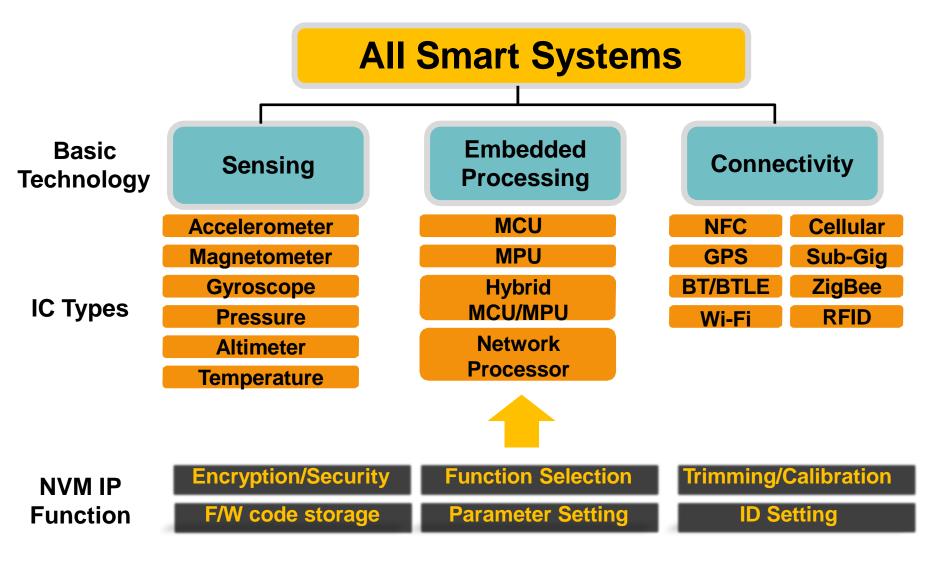
Can NOT Work w/o Security IP/Code



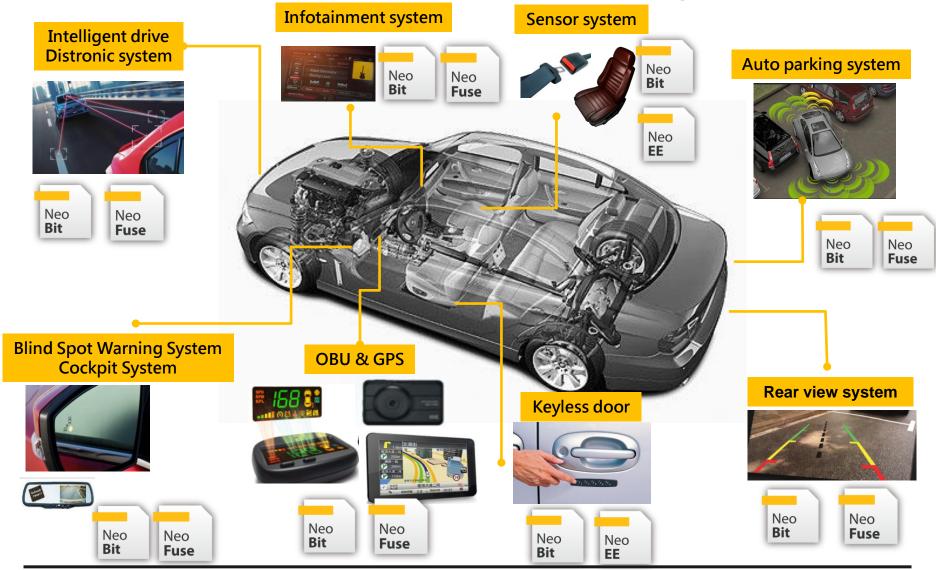
Security with eMemory IPs



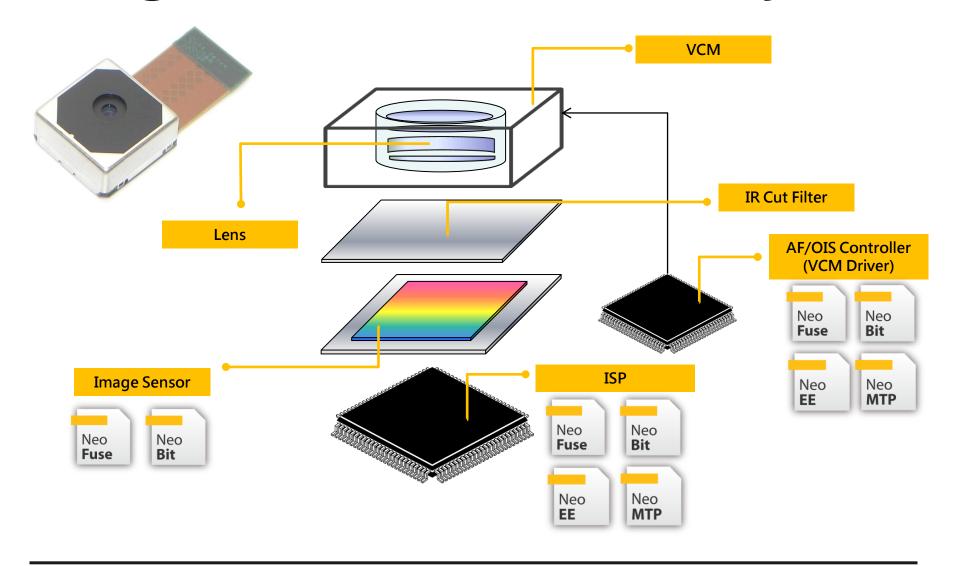
NVM IP Demand in IoT



Autotronics with eMemory IPs

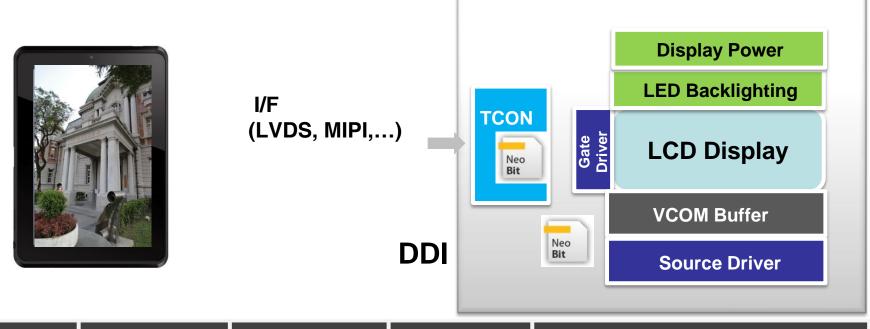


Imager Module with eMemory IPs



Advanced LCD Driver ICs

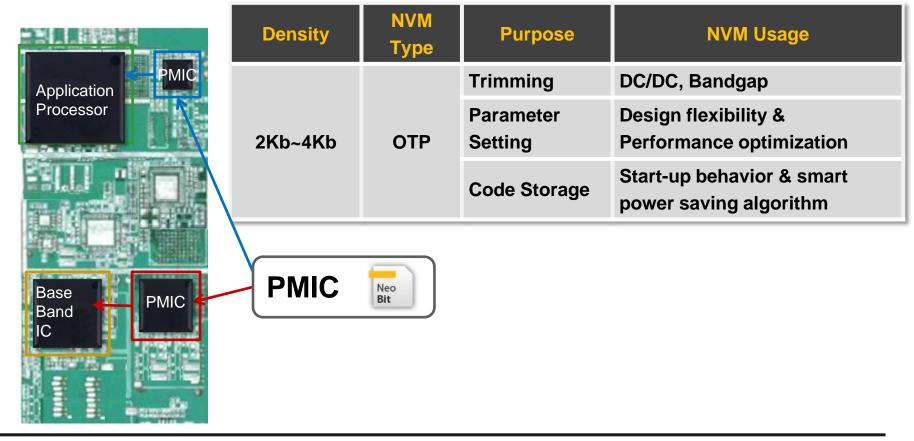
Process Technology: 0.11um HV/80nm HV/55nm HV



Density	Endurance	NVM Type	Purpose	NVM Usage
2K8~4K8		OTP	Trimming	1. Accuracy enhancement
				2. Mismatch cancellation
	1		Code Storage	1. Gamma Correction Table
				2. Timing Control Pattern
				3. Color Engine Enhancement

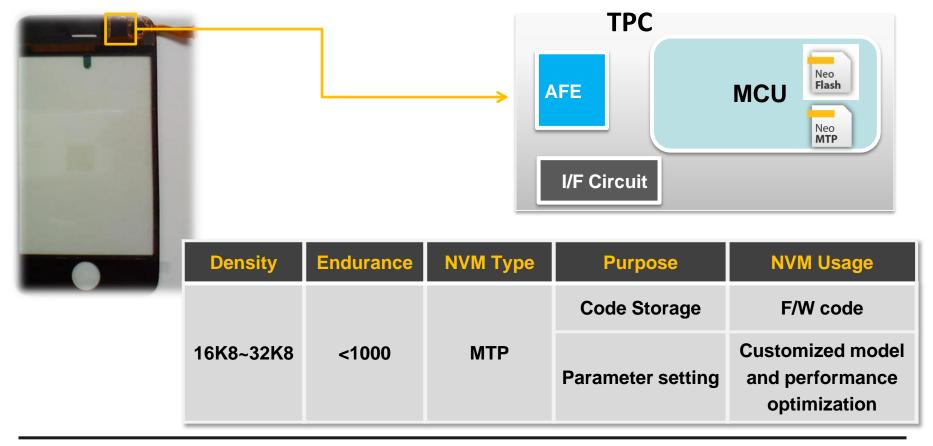
Power Management ICs for Baseband and Application Processor

Process Technology: Advanced 0.25um BCD/ 0.18um BCD/ 0.13um BCD Mature 0.18um/0.16um/0.152um Logic



Touch Panel Controller ICs

Process Technology: 0.16um HV/0.11um G

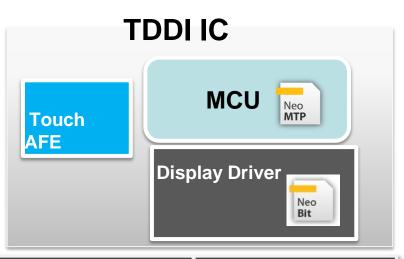


In-Cell Touch Panel Controllers ICs

Process Technology: 0.11um HV/80nm HV/55nm HV



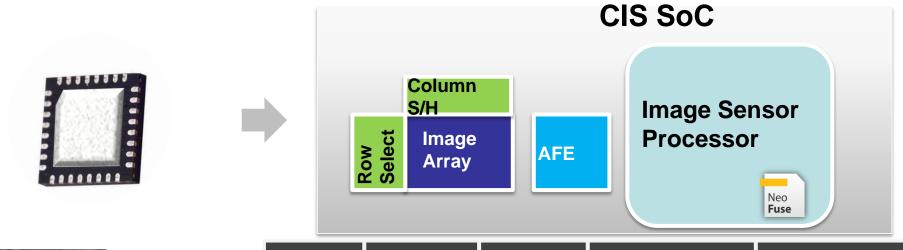


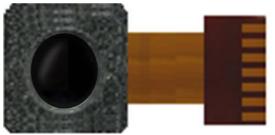


Endurance	NVM Type	Purpose	NVM Usage
2K8~4K8 1	ОТР	Trimming	Accuracy
		Code Storage	Gamma Table
<1000	MTP	Code Storage	Touch F/W Code
		Parameter setting	Performance Optimization
	1	1 OTP	1 OTP Trimming Code Storage Code Storage MTP

CMOS Image Sensor

Process Technology: 0.11um CIS/90nm CIS/65nm CIS

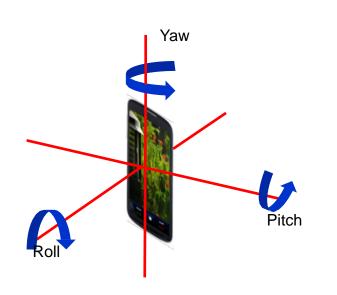


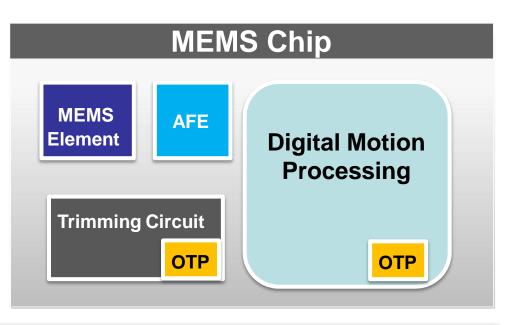


Density	Endurance	NVM Type	Purpose	NVM Usage
2Kb~4Kb	1	ОТР	Identification Setting	Product Code
			Parameter Setting	Start-up Initial Setting
32K8	1	OTP/ROM	Code Storage	Boot Load

MEMS

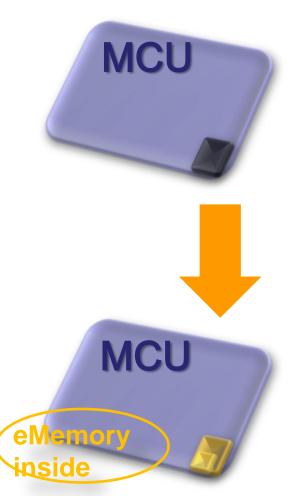
180/160/15x nm HV/Logic for MEMS Controller





Density	NVM Type	Purpose	NVM Usage
2Kb~4Kb	2Kb~4Kb OTP	Trimming	Factory trimming
		Parameter Setting	Signal filtering
	Code Storage	Geometric computation	

Replacement of Embedded Flash for Competitiveness Improvement



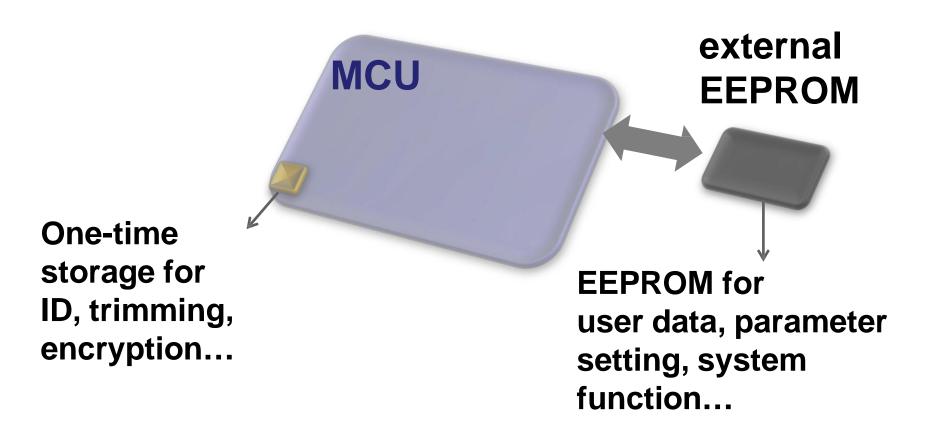
product design & manufacturing by embedded Flash Logic Process + 10 Masks

30% more cost reduction

wafer cost & testing time

product design & manufacturing by Embedded Logic NVM (OTP/MTP) Logic Process

MCU Applications with EEPROM



NeoBit + NeoEE

Hybrid NVM solution (NeoBit + NeoEE) with customized SPEC & optimized size



- One single IP by integration of NeoBit & NeoEE
- Help for system size reduction

3Q14 Wafer Demand by IC Type

IC Type	Equ. to 8-inch wafer (K)	
AP	4964	
PMU	4756	
CIS sensor	4226	
Fingerprint	4000	
Smart card controller	3000	
Base Band	2935	
LCD driver (with TCON)	2013	
Gauge IC	627	
Touch panel controller (C)	556	
Connectivity	395	
STB controller	335	
TV controller	327	
Wifi controller	245	
LED driver	243	
DC-DC/AC-DC	176	
Accelerator sensor controller	124	
Light snesor	121	
Bluetooth controller	121	
Gyroscope sensor controller	104	
TAG IC	76	
DVD controller	67	
MCU (8bits, LV/3.3V)	56	
MCU (8bits, LV/3.3V)	56	
P-Gamma	52	
MCU (8bits, pure 5V)	51	
NB CAM controller	42	
Pressure sensor controller	20	
Touch pad controller	18	
PC CAM controller	15	
Touch panel controller (R)	5	
TCON (w/o driver)	4	

2014.8.29 updated



2015 Outlook

- Applications in major smart phone customer continue their momentum and expand to wearable devices.
- PMICs in Chinese smart phone continue to increase production and expand to new power management applications, such as fast charger and wireless charger.
- TDDI and 55nm LCD Drivers start to ramp up.
- Applications in STB, Fingerprints, and CIS will ramp up in 2H of 2015.

Key Growth Drivers

Growth in value per mobile devices

More chip applications per smartphone/tablet product.

Growth into more markets

- From consumer electronics and mobile devices to wearable devices.
- Adding new NVM product lines further enable more product applications.

Growth in more advanced technology

 Higher royalty per wafer is contributed from more advanced technology nodes.

IoT great era

• Embedded Logic NVM will be a must.

Q & A

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Embedded Wisely, Embedded Widely